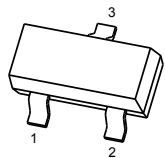


■ Features

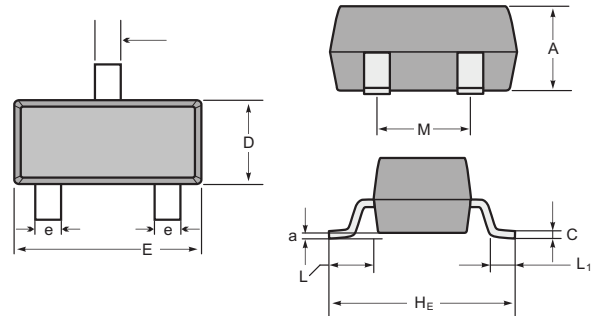
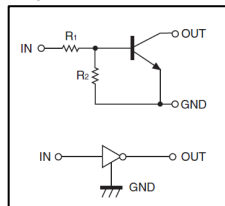
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input.They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



SOT-23

1. IN
2. GND
3. OUT

• Equivalent Circuit



SOT-23 mechanical data

UNIT		A	C	D	E	H _E	e	M	L	L ₁	a
mm	max	1.1	0.15	1.4	3.0	2.6	0.5	1.95	0.55 (ref)	0.36 (ref)	0.0
	min	0.9	0.08	1.2	2.8	2.2	0.3	1.7			0.15
mil	max	43	6	55	118	102	20	77	22 (ref)	14 (ref)	0.0
	min	35	3	47	110	87	12	67			6

■ Absolute Maximum Ratings Ta = 25°C

Symbol	Parameter	DTC143ECAT116	Unit
V _{CC}	Supply Voltage	50	V
V _{IN}	Input Voltage	-10~+30	V
I _O	Output Current	100	mA
P _D	Power Dissipation	200	mW
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

DTC143ECAT116

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	$V_{I(off)}$	$V_{CC}=5V, I_O=100\mu A$	0.5			V
	$V_{I(on)}$	$V_O=0.3V, I_O=20mA$			3	V
Output voltage	$V_{O(on)}$	$I_O/I_I=10mA/0.5mA$			0.3	V
Input current	I_I	$V_I=5V$			1.8	mA
Output current	$I_{O(off)}$	$V_{CC}=50V, V_I=0$			0.5	μA
DC current gain	G_I	$V_O=5V, I_O=10mA$	20			
Input resistance	R_1		3.29	4.7	6.11	k Ω
Resistance ratio	R_2/R_1		0.8	1	1.2	
Transition frequency	f_T	$V_O=10V, I_O=5mA, f=100MHz$		250		MHz

RATING AND CHARACTERISTIC CURVES (DTC143ECAT116)

